NSN 5962-01-199-7510

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View Online at https://aerobasegroup.com/nsn/5962-01-199-7510

Body Length:

1.490 inches

Body Width:

Between 0.500 inches and 0.610 inches

Body Height:

0.217 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and monolithic and ultraviolet erasable and programmed

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

N-type metal oxide-semiconductor logic

Input Circuit Pattern:

17 input

Current Rating Per Characteristic:

50.00 milliamperes forward current, nonrepetitive, peak total value absolute

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.3 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

450.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Prom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

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